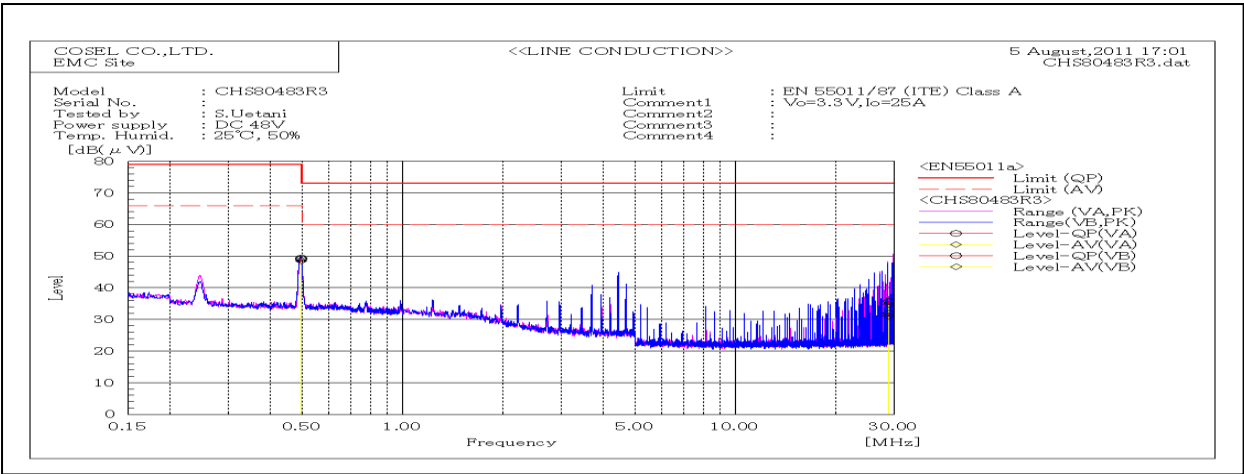
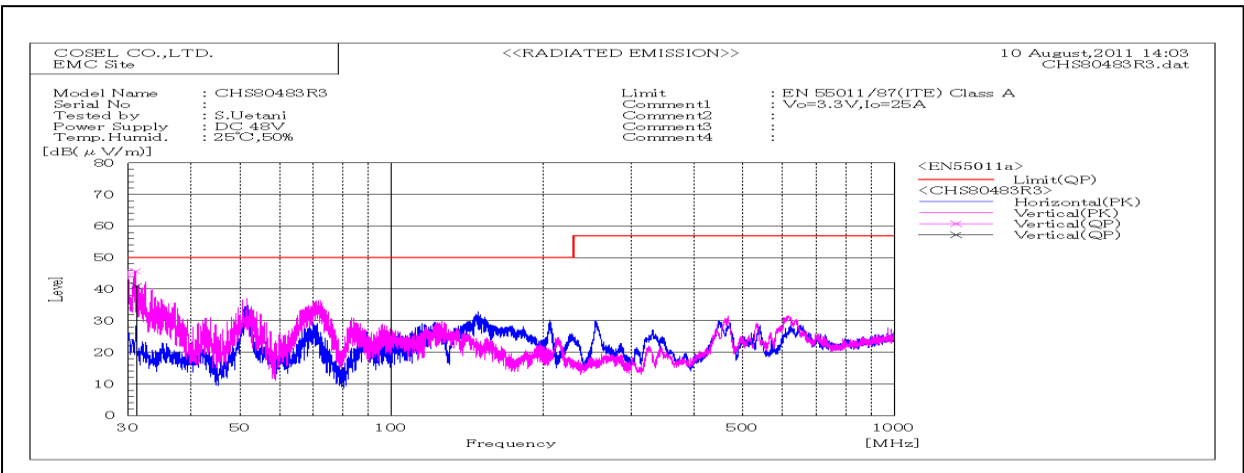


DATA SHEET		Date	27-Apr-21
Model	CHS80483R3	Temp.	25 degreeC
Test	EMI Line conduction & Radiated emission	Humid.	40 %RH
		Tested by	S.Uetani



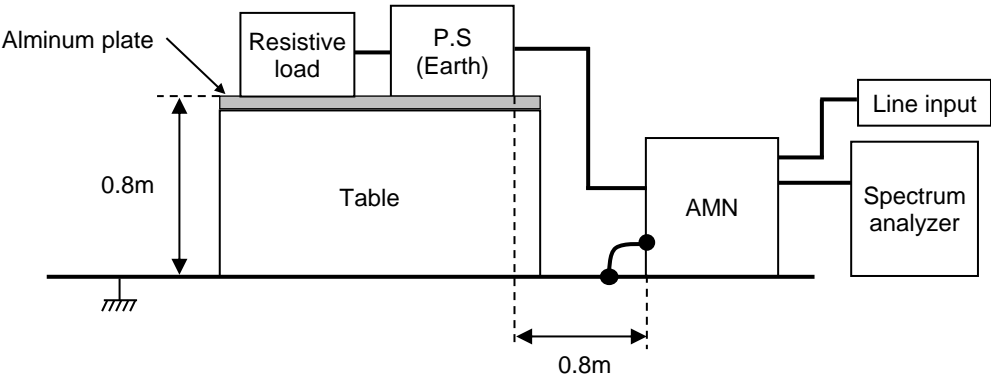
Frequency MHz	Harm	Line Phase	Reading dB(μV)		Factor dB	Level dB(μV)		Limit dB(μV)		Margin dB		Pass/ Fail	Remark
			QP	AV		QP	AV	QP	AV	QP	AV		
0.49619		VA	39.4	38.8	10.1	49.5	48.9	79	66	29.5	17.1	Pass	
0.49609		VB	39	38.4	10.1	49.1	48.5	79	66	29.9	17.5	Pass	
28.8738		VA	24.7	23.7	11	35.7	34.7	73	60	37.3	25.3	Pass	
28.867		VB	20.9	20.1	11	31.9	31.1	73	60	41.1	28.9	Pass	



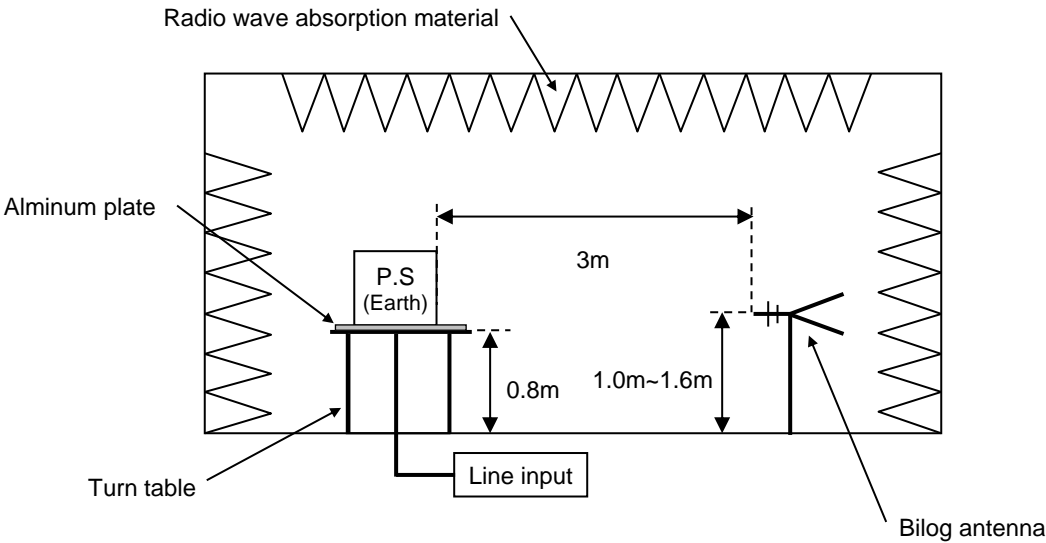
Frequency MHz	Harm	Polariz ation	Stabili ty	Reading dB(μV)		Space Loss dB	Level dB(mW)		Margin dB	Pass/ Fail	Height cm	Angle deg	Remark
				QP	AV		QP	AV					
31.129		V	Stable	55	-14		41	50	9	Pass	102	171	

DATA SHEET		Date	27-Apr-21
Model	Circuit used for measurement	Temp.	25 degreeC
Test	EMI Line conduction & Radiated emission	Humid.	40 %RH
		Tested by	S.Uetani

1. Line conduction



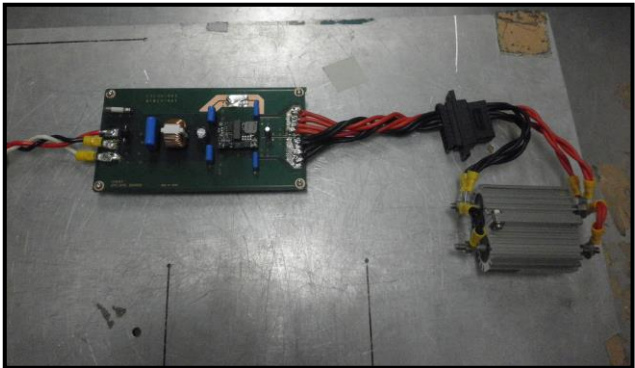
2. Radiated emission



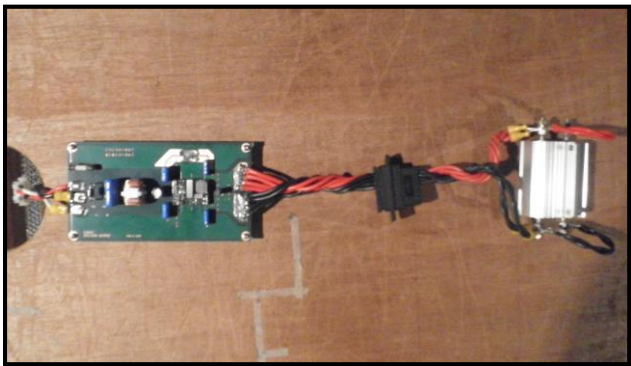
TEST :EMI  
Model Name :CHS80483R3

Date 2011/10/4

○Photographs of Test Set-Up  
LINE CONDUCTION



RADIATED EMISSION



○ Testing circuitry

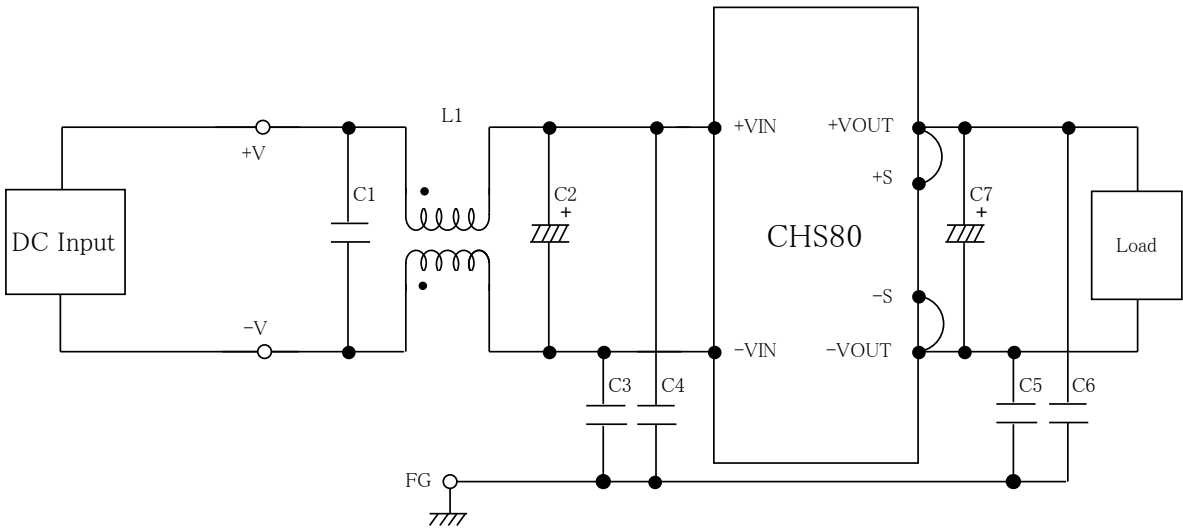


Fig.1 Testing circuitry

- L1 : 1mH SC-05-10J (TOKIN)
- C1 : 250V 2.2  $\mu$ F FPD22E225J4 (NITSUKO)
- C2 : 100V 33  $\mu$ F PWseries (nichicon)
- C3,C4 : 630V 0.068  $\mu$ F FPD22J683J4 (NITSUKO)
- C5,C6 : 630V 0.033  $\mu$ F FPD22J333J4 (NITSUKO)
- C7 : 50V 10  $\mu$ F PMseries (nichicon)